

PSMN2R0-60PS

N-channel 60 V 2.2 mΩ standard level MOSFET in TO-220
4 October 2012 Product data sheet

1. Product profile

1.1 General description

Standard level N-channel MOSFET in a TO-220 package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources

1.3 Applications

- DC-to-DC converters
- Load switching
- Motor control
- Server power supplies

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	60	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	-	120	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	338	W
Tj	junction temperature			-55	-	175	°C
Static characte	eristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12	[2]	-	1.8	2.2	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 12; Fig. 13		-	3	3.5	mΩ
Dynamic chara	Dynamic characteristics						
Q_{GD}	gate-drain charge	V_{GS} = 10 V; I_D = 75 A; V_{DS} = 30 V;		-	32	45	nC
Q _{G(tot)}	total gate charge	Fig. 14; Fig. 15		-	137	192	nC



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Avalanche rug	gedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 120 A; $V_{sup} \le$ 60 V; R_{GS} = 50 Ω; Unclamped	-	-	913	mJ

- [1] Continuous current limited by package[2] Measured 3 mm from package.

Pinning information

Table 2. **Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	mb	D I
2	D	drain	704	
3	S	source		G—U: 4
mb	D	mounting base; connected to drain		mbb076 S
			TO-220AB (SOT78)	

Ordering information

Table 3. **Ordering information**

Type number	Package		
	Name	Description	Version
PSMN2R0-60PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78

Marking

Table 4. **Marking codes**

Type number	Marking code
PSMN2R0-60PS	PSMN2R0-60PS

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	60	V
V_{DGR}	drain-gate voltage	$T_j \ge 25$ °C; $T_j \le 175$ °C; $R_{GS} = 20$ kΩ		-	60	V
V_{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	[1]	-	120	Α
		V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	120	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	1135	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	338	W
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
$T_{sld(M)}$	peak soldering temperature			-	260	°C
Source-dra	in diode					
Is	source current	T _{mb} = 25 °C	[1]	-	120	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	1135	Α
Avalanche	ruggedness	1	-1	-		
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 120 A; V_{sup} ≤ 60 V; R_{GS} = 50 Ω ; Unclamped		-	913	mJ

^[1] Continuous current limited by package

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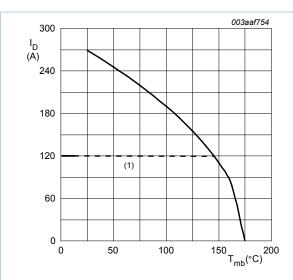


Fig. 1. Continuous drain current as a function of mounting base temperature.

 $V_{\it GS} \ge 10~{
m V};$ (1) Capped at 120 A due to package

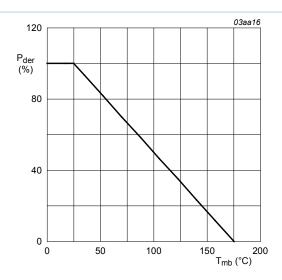


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \,\%$$

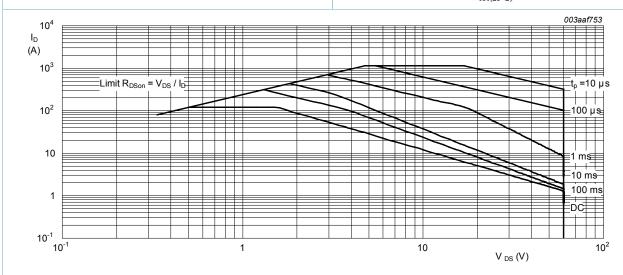


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 T_{mb} = 25 °C; I_{DM} is a single pulse; Capped at 120 A due to package

6. Thermal characteristics

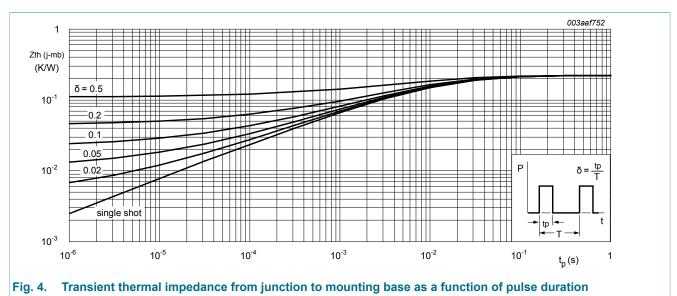
Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	0.22	0.44	K/W

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	Vertical in free air	-	60	-	K/W



7. Characteristics

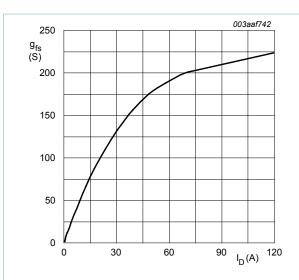
Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static charac	cteristics						
V _{(BR)DSS}	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$		54	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C		60	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 175 °C; Fig. 10		1	-	-	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 11; Fig. 10		2	3	4	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 10		-	-	4.6	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C		-	0.03	10	μA
		V _{DS} = 60 V; V _{GS} = 0 V; T _j = 175 °C		-	-	500	μΑ
I _{GSS}	gate leakage current	V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C		-	-	100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C		-	-	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12	[1]	-	1.8	2.2	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 175 °C; Fig. 12; Fig. 13		-	4.3	5.1	mΩ

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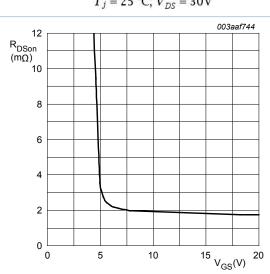
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _{GS} = 10 V; I _D = 25 A; T _j = 100 °C; Fig. 12; Fig. 13	-	3	3.5	mΩ
R_G	gate resistance	f = 1 MHz	0.45	0.9	1.8	Ω
Dynamic ch	naracteristics	1	'			
Q _{G(tot)}	total gate charge	I _D = 75 A; V _{DS} = 30 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	137	192	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	129	181	nC
Q_{GS}	gate-source charge	I _D = 75 A; V _{DS} = 30 V; V _{GS} = 10 V	-	48	68	nC
Q _{GS(th)}	pre-threshold gate- source charge	I _D = 75 A; V _{DS} = 30 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	29	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	19	-	nC
Q_{GD}	gate-drain charge		-	32	45	nC
$V_{GS(pl)}$	gate-source plateau voltage	V _{DS} = 30 V; <u>Fig. 14</u> ; <u>Fig. 15</u>	-	5.7	-	V
C _{iss}	input capacitance	V _{DS} = 30 V; V _{GS} = 0 V; f = 1 MHz;	-	9997	13500	pF
Coss	output capacitance	T _j = 25 °C; <u>Fig. 16</u>	-	1210	1640	pF
C _{rss}	reverse transfer capacitance		-	594	835	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; R_{L} = 0.4 Ω ; V_{GS} = 10 V;	-	42	63	ns
t _r	rise time	$R_{G(ext)} = 4.7 \Omega; I_D = 75 A$	-	56	84	ns
$t_{d(off)}$	turn-off delay time		-	115	173	ns
t _f	fall time		-	49	74	ns
Source-drai	in diode		,			
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 17$	-	8.0	1.2	V
t _{rr}	reverse recovery time	I_S = 25 A; dI_S/dt = -100 A/ μ s; V_{GS} = 0 V; V_{DS} = 30 V	-	57	75	ns
Q _r	recovered charge	I_S = 25 A; dI_S/dt = -100 A/ μ s; V_{GS} = 0 V; V_{DS} = 30 V	-	80	104	nC

^[1] Measured 3 mm from package.



Forward transconductance as a function of drain current; typical values





Drain-source on-state resistance as a function Fig. 7. of gate-source voltage; typical values

$$T_j = 25$$
 °C; $I_D = 25$ A

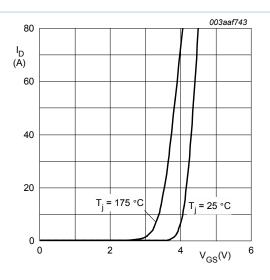


Fig. 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

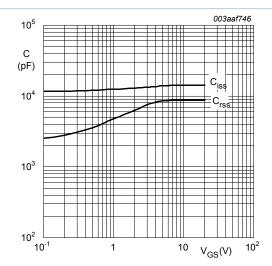


Fig. 8. Input and reverse transfer capacitances as a function of gate-source voltage, typical values

$$V_{DS} = 0 \text{ V; } f = 1 \text{ MHz}$$

7/14

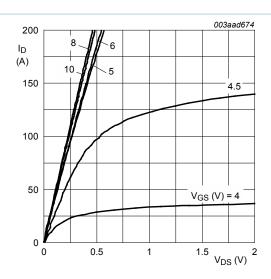


Fig. 9. Output characteristics: drain current as a function of drain-source voltage; typical values



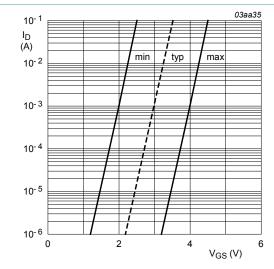


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25\,^{\circ}C; V_{DS} = 5V$$

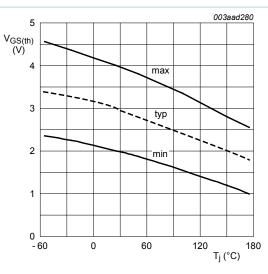


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$$

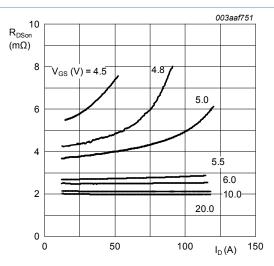
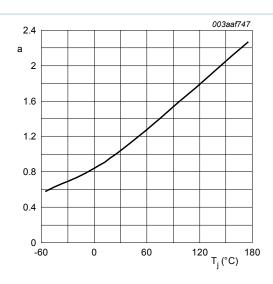


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25\,^{\circ}C$$

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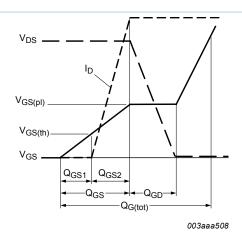
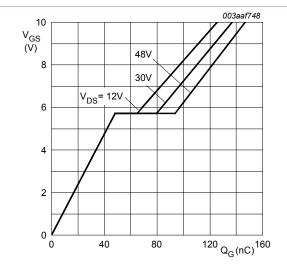


Fig. 14. Gate charge waveform definitions

Fig. 13. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25$$
 °C; $I_D = 25$ A





$$T_j = 25$$
 °C; $I_D = 75$ A

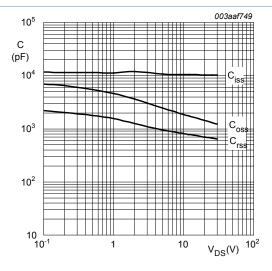


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0 \text{ V; } f = 1 \text{ MHz}$$

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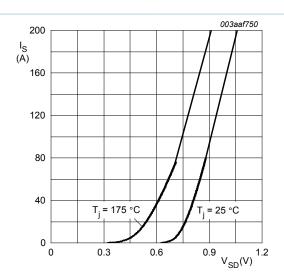
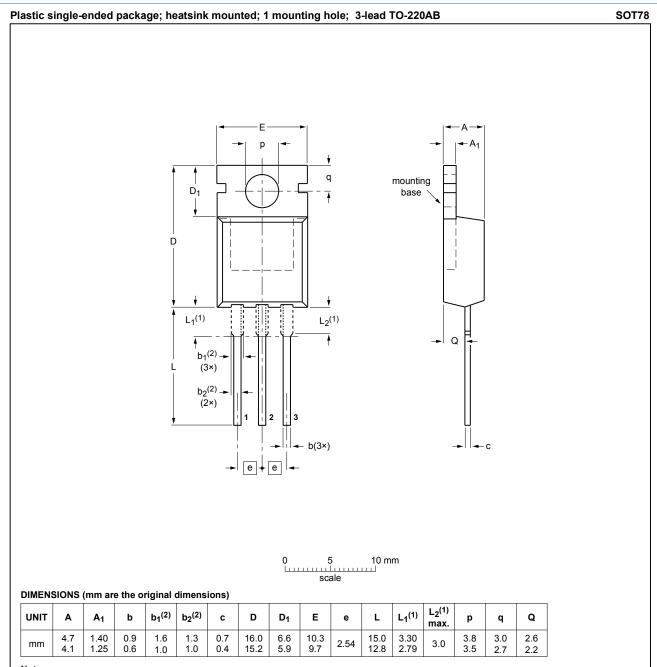


Fig. 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$$V_{GS} = 0 \text{ V}$$

8. Package outline



Notes

- 1. Lead shoulder designs may vary.
- Dimension includes excess dambar.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE
SOT78		3-lead TO-220AB	SC-46			08-04-23 08-06-13

Fig. 18. Package outline TO-220AB (SOT78)

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Document status [1][2]	Product status [3]	Definition
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